

preliminary

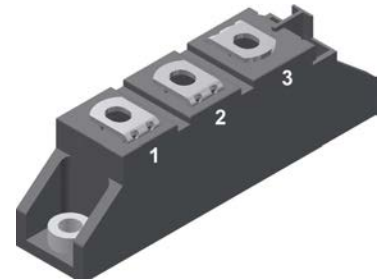
HiPerFRED Module

 $V_{RRM} = 600\text{ V}$
 $I_{FAV} = 2 \times 95\text{ A}$
 $t_{rr} = 35\text{ ns}$

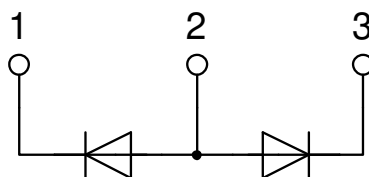
Common Anode

Part number

MPK95-06DA



Backside: isolated

Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low I_{rm} -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low I_{rm} reduces:
 - Power dissipation within the diode
 - Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

Package: TO-240AA

- Isolation Voltage: 4800 V~
- Industry standard outline
- RoHS compliant
- Height: 30 mm
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

Disclaimer Notice

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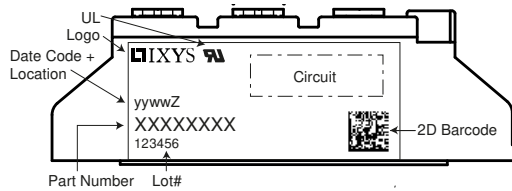


Fast Diode				Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
V_{RSM}	max. non-repetitive reverse blocking voltage	$T_{VJ} = 25^{\circ}C$			600	V	
V_{RRM}	max. repetitive reverse blocking voltage	$T_{VJ} = 25^{\circ}C$			600	V	
I_R	reverse current, drain current	$V_R = 600 V$	$T_{VJ} = 25^{\circ}C$		1,3	mA	
		$V_R = 600 V$	$T_{VJ} = 125^{\circ}C$		5	mA	
V_F	forward voltage drop	$I_F = 50 A$	$T_{VJ} = 25^{\circ}C$		1,73	V	
		$I_F = 100 A$			1,89	V	
		$I_F = 50 A$	$T_{VJ} = 125^{\circ}C$		1,22	V	
		$I_F = 100 A$			1,40	V	
I_{FAV}	average forward current	$T_C = 110^{\circ}C$ rectangular $d = 0.5$	$T_{VJ} = 150^{\circ}C$		95	A	
V_{FO}	threshold voltage	} for power loss calculation only	$T_{VJ} = 150^{\circ}C$		0,98	V	
r_F	slope resistance				2,3	mΩ	
R_{thJC}	thermal resistance junction to case				0,58	K/W	
R_{thCH}	thermal resistance case to heatsink			0,10		K/W	
P_{tot}	total power dissipation		$T_C = 25^{\circ}C$		215	W	
I_{FSM}	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{ sine}; V_R = 0 V$	$T_{VJ} = 45^{\circ}C$		1,20	kA	
C_J	junction capacitance	$V_R = 600V \quad f = 1 \text{ MHz}$	$T_{VJ} = 25^{\circ}C$		70	pF	
I_{RM}	max. reverse recovery current	} $I_F = 130 A; V_R = 100 V$ $-di_F/dt = 300 A/\mu s$	$T_{VJ} = 25^{\circ}C$		4	A	
			$T_{VJ} = 100^{\circ}C$		5,5	A	
t_{rr}	reverse recovery time		$T_{VJ} = 25^{\circ}C$		35	ns	
			$T_{VJ} = 100^{\circ}C$		tbd	ns	



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Package TO-240AA				Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
I_{RMS}	RMS current	per terminal			200	A	
T_{VJ}	virtual junction temperature		-40		150	°C	
T_{op}	operation temperature		-40		125	°C	
T_{stg}	storage temperature		-40		125	°C	
Weight					76	g	
M_D	mounting torque		2,5		4	Nm	
M_T	terminal torque		2,5		4	Nm	
$d_{Spp/Apb}$	creepage distance on surface striking distance through air	terminal to terminal	13,0	9,7		mm	
$d_{Spb/Apb}$		terminal to backside	16,0	16,0		mm	
V_{ISOL}	isolation voltage	t = 1 second			4800	V	
		t = 1 minute	50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA		4000	V	

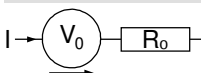


Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MPK95-06DA	MPK95-06DA	Box	36	501058

Equivalent Circuits for Simulation

* on die level

$T_{VJ} = 150^{\circ}C$



Fast Diode

$V_{0\ max}$ threshold voltage

0,98

V

$R_{0\ max}$ slope resistance *

mΩ



Outlines TO-240AA

